# PDEs and electronic structure calculations

Eric CANCES

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First-principle molecular simulation is becoming an essential tool in Chemistry, Materials Science, Molecular Biology and Nanosciences

### Some objective facts :

- The most cited four articles in Physics are
  1. Kohn & Sham, PR 1965 Density Functional Theory (LDA)
  2. Hohenberg & Kohn, PR 1964 Density Functional Theory
  3. Perdew & Zunger, PRB 1981 Density Functional Theory (GGA)
  4. Ceperley & Alder, PRL 1980 Quantum Monte Carlo
- W. Kohn and J. Pople shared the 1998 Nobel Price in Chemistry
- First-principle molecular simulation utilizes more than 20% of the resources available in scientific computing centers
- Only a handful of Mathematicians are working in this field

First-principle (or *ab initio*) molecular simulation

In the absence of nuclear reactions, matter can be described as an assembly of quantum nuclei and electrons interacting through the Coulomb potential : No empirical parameters !

Atomic units : 
$$\hbar = 1$$
,  $m_e = 1$ ,  $e = 1$ ,  $\frac{1}{4\pi\varepsilon_0} = 1$ 

Electrons and nuclei

Electrons : mass  $m_e = 1$ , charge -1,

Nucleus k: mass  $1836 \le m_k \le 400\,000$ , charge  $z_k \in \mathbb{N}^*$ 

1

Born-Oppenheimer approximation (classical nuclei, quantum electrons)

Atomic positions and momenta :  $({\mathbf{R}_k(t)}, {\mathbf{P}_k(t)}) \in \mathbb{R}^{3M} \times \mathbb{R}^{3M}$ 

$$\begin{cases} \frac{d\mathbf{R}_{k}}{dt}(t) = \frac{\partial H_{\text{nuc}}}{\partial \mathbf{P}_{k}} = \frac{\mathbf{P}_{k}(t)}{m_{k}}\\ \frac{d\mathbf{P}_{k}}{dt}(t) = -\frac{\partial H_{\text{nuc}}}{\partial \mathbf{R}_{k}} = -\nabla_{\mathbf{R}_{k}}W(\mathbf{R}_{1}(t), \cdots, \mathbf{R}_{M}(t)) \end{cases}$$

$$H_{\text{nuc}}(\{\mathbf{R}_k\}, \{\mathbf{P}_k\}) = \sum_{k=1}^{M} \frac{|\mathbf{P}_k|^2}{2 m_k} + W(\mathbf{R}_1, \cdots, \mathbf{R}_M)$$

 $W(\mathbf{R}_1, \cdots, \mathbf{R}_M)$  effective potential (free of empirical parameters)

#### Introduction

Ab initio interatomic potentials and forces

$$W(\mathbf{R}_{1}, \cdots, \mathbf{R}_{M}) = E_{\{\mathbf{R}_{k}\}}^{0} + V_{\{\mathbf{R}_{k}\}}^{nn}$$
$$\nabla_{\mathbf{R}_{k}}W(\mathbf{R}_{1}, \cdots, \mathbf{R}_{M}) = \int_{\mathbb{R}^{3}} \rho_{\{\mathbf{R}_{k}\}}^{0} (\mathbf{r}) \nabla_{\mathbf{R}_{k}} V_{\{\mathbf{R}_{k}\}}^{ne} (\mathbf{r}) d\mathbf{r} + \nabla_{\mathbf{R}_{k}} V_{\{\mathbf{R}_{k}\}}^{nn}$$

$$V_{\{\mathbf{R}_k\}}^{\mathrm{nn}} = \sum_{1 \le k < l \le M} \frac{z_k z_l}{|\mathbf{R}_k - \mathbf{R}_l|}$$
 nuclear Coulomb repulsion energy  
 $V_{\{\mathbf{R}_k\}}^{\mathrm{ne}}(\mathbf{r}) = -\sum_{k=1}^M \frac{z_k}{|\mathbf{r} - \mathbf{R}_k|}$  nuclear Coulomb potential

 $E^0_{\{{\bf R}_k\}}$  and  $\rho^0_{\{{\bf R}_k\}}({\bf r})$  electronic ground state energy and density

From now on, the positions  $\{\mathbf{R}_k\}$  of the nuclei are considered as fixed

In order to simplify the notation, we set

$$E^0 = E^0_{\{\mathbf{R}_k\}}$$

$$\rho^0(\mathbf{r}) = \rho^0_{\{\mathbf{R}_k\}}(\mathbf{r})$$

$$V^{\mathrm{ne}}(\mathbf{r}) = V^{\mathrm{ne}}_{\{\mathbf{R}_k\}}(\mathbf{r}) = -\sum_{k=1}^M \frac{z_k}{|\mathbf{r} - \mathbf{R}_k|}$$

#### Introduction

 $E^0$  is the lowest eigenvalue of the electronic Schrödinger equation

$$H_N \Psi^0 = E^0 \Psi^0$$

where the electronic Hamiltonian is given by

$$H_N = -\sum_{i=1}^N \frac{1}{2} \Delta_{\mathbf{r}_i} - \sum_{i=1}^N \sum_{k=1}^M \frac{z_k}{|\mathbf{r}_i - \mathbf{R}_k|} + \sum_{1 \le i < j \le N} \frac{1}{|\mathbf{r}_i - \mathbf{r}_j|}$$

and where the electronic ground state wavefunction  $\Psi^0$  satisfies – the Pauli principle

$$\forall i < j, \qquad \Psi^0(\cdots, \mathbf{r}_j, \cdots, \mathbf{r}_i, \cdots) = -\Psi^0(\cdots, \mathbf{r}_i, \cdots, \mathbf{r}_j, \cdots)$$

- the normalization condition

$$\int_{\mathbb{R}^{3N}} |\Psi^0(\mathbf{r}_1,\cdots,\mathbf{r}_N)|^2 \, d\mathbf{r}_1\cdots d\mathbf{r}_N = 1$$

#### Introduction

# $\rho^0({\bf r})$ is the density associated with $\Psi^0$

The density associated with a function  $\Psi(\mathbf{r}_1, \cdots, \mathbf{r}_N)$  satisfying – the Pauli principle

$$\forall i < j, \qquad \Psi(\cdots, \mathbf{r}_j, \cdots, \mathbf{r}_i, \cdots) = -\Psi(\cdots, \mathbf{r}_i, \cdots, \mathbf{r}_j, \cdots)$$

- the normalization condition

$$\int_{\mathbb{R}^{3N}} |\Psi(\mathbf{r}_1,\cdots,\mathbf{r}_N)|^2 \, d\mathbf{r}_1\cdots d\mathbf{r}_N = 1$$

is the function  $\rho_{\Psi}(\mathbf{r})$  defined by

$$\rho_{\Psi}(\mathbf{r}) = N \int_{\mathbb{R}^{3(N-1)}} |\Psi(\mathbf{r}, \mathbf{r}_2, \cdots, \mathbf{r}_N)|^2 d\mathbf{r}_2 \cdots d\mathbf{r}_N$$

It holds

$$ho_{\Psi}(\mathbf{r}) \ge 0$$
 and  $\int_{\mathbb{R}^3} 
ho_{\Psi}(\mathbf{r}) \, d\mathbf{r} = N$ 

#### Strengths of the model :

- It allows to simulate a wide variety of phenomena
- It does not contain any parameter specific to the system
- It is extremely accurate
  - Ionization energy of Helium (Korobov & Yelkhovsky PRL 2001) - calculations : 5 945 262 288 MHz, 5 945 204 223 MHz with RC - exp. : 5 945 204 238 MHz (1997), 5 945 204 356 MHz (1998)

#### Weaknesses of the model :

- The Schrödinger equation  $H_N \Psi = E \Psi$  is a 3N-dimensional PDE
- Chemical accuracy is required
   example : atomization energy of water

$$\Delta E_{\text{H}_2\text{O}} = E_{\text{H}_2\text{O}} - 2E_{\text{H}} - E_{\text{O}}$$
  
= -76.4389 - 2 × (-0.5) - (-75.0840) = -0.3549 a.u.

#### Introduction

Methods for electronic structure calculations



### Ab initio simulations today

A few atoms (small organic molecules) : spectroscopic accuracy
A few dozens of first- or second-row atoms : chemical accuracy
Several hundreds / a few thousands of atoms : qualitative results
W.R.(?) : 11.8 million-atom (1.04×10<sup>12</sup> grid points) DFT simulation (A. Nakano et al., Int. J. High Perform. C. Appl. 2008)





1 - Linear scaling algorithms



$$E^{0} = \sum_{i=1}^{N} \varepsilon_{i}, \qquad \Psi^{0}(\mathbf{r}_{1}, \cdots, \mathbf{r}_{N}) = \frac{1}{\sqrt{N!}} \det(\phi_{i}(\mathbf{r}_{j})), \qquad \rho^{0}(\mathbf{r}) = \sum_{i=1}^{N} |\phi_{i}(\mathbf{r})|^{2}$$

## 1 - Linear scaling algorithms

For non-interacting electrons, 
$$E^0 = \sum_{i=1}^N \varepsilon_i$$
 and  $\rho^0(\mathbf{r}) = \sum_{i=1}^N |\phi_i(\mathbf{r})|^2$  with

$$\begin{cases} -\frac{1}{2}\Delta\phi_i + V^{ne}\phi_i = \varepsilon_i\phi_i \\ \int_{\mathbb{R}^3}\phi_i\phi_j = \delta_{ij} \\ \varepsilon_1 < \varepsilon_2 \leq \cdots \leq \varepsilon_N \quad \text{lowest } N \text{ eigenvalues of } h = -\frac{1}{2}\Delta + V^{ne} \end{cases}$$

## $\rightarrow$ Linear eigenvalue problem

Galerkin approximation in atomic orbital basis sets  $(\chi_{\mu})_{1 \leq \mu \leq N_b}$ 



dimension of the approximation space :  $N_b$   $2 \times N \leq N_b \leq 5 \times N$ 

$$\begin{cases} H\Phi_i = \varepsilon_i S\Phi_i & H = [\langle \chi_\mu | h | \chi_\nu \rangle] \in \mathbb{R}^{N_b \times N_b}, \quad S = [\langle \chi_\mu | \chi_\nu \rangle] \in \mathbb{R}^{N_b \times N_b} \\ \Phi_i^{\mathrm{T}} S\Phi_j = \delta_{ij} & \\ \varepsilon_1 < \varepsilon_2 \leq \cdots \leq \varepsilon_N & \text{lowest } N \text{ eigenvalues of } H\Phi = \varepsilon S\Phi \end{cases}$$

Assume for simplicity that  $S = I_{N_b}$  (orthonormal basis)  $H = [\langle \chi_{\mu} | h | \chi_{\nu} \rangle]$  symmetric  $N_b \times N_b$  matrix with  $N_b \sim 5N$ 

$$\begin{cases} E^{0} = \sum_{i=1}^{N} \varepsilon_{i} = (HD), \quad \rho^{0}(\mathbf{r}) = \sum_{i=1}^{N} \left| \sum_{\mu=1}^{N_{b}} \Phi_{i,\mu} \chi_{\mu}(\mathbf{r}) \right| = \sum_{\mu,\nu} D_{\mu,\nu} \chi_{\mu}(\mathbf{r}) \chi_{\nu}(\mathbf{r}) \\ D = \sum_{i=1}^{N} \Phi_{i} \Phi_{i}^{\mathrm{T}} \qquad (\Phi_{1}, \cdots, \Phi_{N}) \\ H\Phi_{i} = \varepsilon_{i} \Phi_{i} \\ \Phi_{i}^{\mathrm{T}} \Phi_{j} = \delta_{ij} \\ \varepsilon_{1} \leq \varepsilon_{2} \leq \cdots \leq \varepsilon_{N} \qquad N \qquad H \end{cases}$$

– for a generic matrix H: algorithmic complexity in  $N^3$ 

- for a sparse matrix : algorithmic complexity in  $N^2$
- for some hamiltonian matrices : algorithmic complexity in N

#### Fundamental remarks :

- 1. We do not need to compute the individual eigenvectors but only the orthogonal projector D
- 2. For insulators and semiconductors, the matrix D is sparse

## Formulation in D

 $D_{\text{opt}} = \mathcal{H}(\varepsilon_F - H), \qquad \mathcal{H}$  Heaviside function

 $D_{\text{opt}} = \operatorname{arginf} \left\{ \operatorname{Tr}(HD), \quad D \in \mathcal{M}_S(N_b), \quad D^2 = D, \quad \operatorname{Tr}(D) = N \right\}$ 



Some alternatives

to brute force diagonalization

- Polynomial or rational fraction approximation of  $\mathcal{H}(\varepsilon_F H)$ : FOE, FOP (Goedecker 1999)
- Exact penalization methods : DMM (Li, Numes, Vanderbilt 1993)
- Domain decomposition methods :
  - Divide and Conquer (Yang, Lee 1992)
  - Multilevel Domain Decomposition
    - (Barrault, Bencteux, E.C., Le Bris, Hager, 2007)
  - Fragment method (Zhao, Meza, Wang 2008)

Linear scaling on grids : García-Cervera, Lu, Xuan, E (2008)

Formulation in  $C : D_{opt} = C_{opt}C_{opt}^{T}$ , where  $C_{opt}$  is solution to  $\inf \left\{ \mathbf{Tr}(HCC^{T}), \quad C \in \mathcal{M}(N_{b}, N), \quad C^{T}C = I_{N} \right\}$ (1)

Rotational invariance : if  $C_{opt}$  is solution, so is  $C_{opt}U$ , for any orthogonal matrix  $U \in U(N)$ 

Localized orbitals. For an insulator  $(\varepsilon_{N+1} - \varepsilon_N > 0 \text{ not too small})$ , there exists a matrix  $C_{\text{loc}}$  such that  $D_{\text{opt}} = C_{\text{loc}}C_{\text{loc}}^{\text{T}}$  where the matrix  $C_{\text{loc}}$  is made of almost locally supported vectors



#### 1 - Linear scaling algorithms

For insulators, it suffices to solve

$$\inf \left\{ \mathbf{Tr}(HCC^{\mathrm{T}}), \quad C \in \mathcal{M}(N_b, N), \quad C^{\mathrm{T}}C = I_N \right\}$$
(2)

for matrices C of the form



#### 1 - Linear scaling algorithms

Comparison with LAPACK and DMM (sequential codes)



Parallel MDD code (G. Bencteux, EDF) :

5 million atom polyethylen chain , STO-3G  $(17.5 \times 10^6 \text{ AO})$ solution of the linear subproblem in 60 minutes on 1024 processors

- 1. Our approach (exact decomposition of the energy, localization of the constraints) provides a general framework for constructing efficient, variational, linear scaling, domain decomposition algorithms
- 2. We have demonstrated the efficiency of this general strategy by proposing a multilevel domain decomposition algorithm (MDD) performing very well on a benchmark of linear molecules
- 3. The convergence properties of the MDD algorithm have been established in a simplified setting (G. Bencteux, E.C., W.W. Hager and C. Le Bris, submitted)
- 4. Relaxing the orthonormality constraints on the localized orbitals would further increase the performance of the MDD algorithm
- 5. The implementation of a 3D version of the MDD algorithm is a work in progress (G. Bencteux, EDF and Cermics, ANR Parmat)

2 - Density Functional Theory

## Constrained optimization formulation of the non-interacting model

For non-interacting electrons, the ground state energy and density can be obtained by solving

$$\inf \left\{ E^{\mathrm{NI}}(\Phi), \quad \Phi = (\phi_1, \cdots, \phi_N) \in (H^1(\mathbb{R}^3))^N, \quad \int_{\mathbb{R}^3} \phi_i \phi_j = \delta_{ij} \right\}$$
$$E^{\mathrm{NI}}(\Phi) = \sum_{i=1}^N \langle \phi_i | h | \phi_i \rangle = \sum_{i=1}^N \frac{1}{2} \int_{\mathbb{R}^3} |\nabla \phi_i|^2 + \int_{\mathbb{R}^3} \rho_\Phi V^{\mathrm{ne}}$$
$$V^{\mathrm{ne}}(\mathbf{r}) = -\sum_{k=1}^M \frac{z_k}{|\mathbf{r} - \mathbf{R}_k|} \qquad \rho_\Phi(\mathbf{r}) = \sum_{i=1}^N |\phi_i(\mathbf{r})|^2$$

#### The case of interacting electrons

In the Kohn-Sham model, the ground state energy and density are obtained by solving

$$\inf \left\{ E^{\mathrm{KS}}(\Phi), \quad \Phi = (\phi_1, \cdots, \phi_N) \in (H^1(\mathbb{R}^3))^N, \quad \int_{\mathbb{R}^3} \phi_i \phi_j = \delta_{ij} \right\}$$
$$E^{\mathrm{KS}}(\Phi) = \sum_{i=1}^N \frac{1}{2} \int_{\mathbb{R}^3} |\nabla \phi_i|^2 + \int_{\mathbb{R}^3} \rho_\Phi V^{\mathrm{ne}} + \frac{1}{2} \int_{\mathbb{R}^3} \int_{\mathbb{R}^3} \frac{\rho_\Phi(\mathbf{r}) \rho_\Phi(\mathbf{r}')}{|\mathbf{r} - \mathbf{r}'|} \, d\mathbf{r} \, d\mathbf{r}' + E_{\mathrm{xc}}[\rho_\Phi]$$

$$V^{\mathrm{ne}}(\mathbf{r}) = -\sum_{k=1}^{M} \frac{z_k}{|\mathbf{r} - \mathbf{R}_k|} \qquad \rho_{\Phi}(\mathbf{r}) = \sum_{i=1}^{N} |\phi_i(\mathbf{r})|^2$$

 $E_{\rm xc}$ : exchange-correlation functional Hohenberg-Kohn theorem : existence of an exact XC functional Prototypical approximate XC functional :  $E_{\rm xc}^{\rm X\alpha}[\rho] = -C_{\rm X} \int_{\mathbb{R}^3} \rho^{4/3}(\mathbf{r}) \, d\mathbf{r}$ 

## **2** - Density Functional Theory

# Kohn-Sham equations ('insulating' case)

$$\begin{split} & \left\{ \begin{array}{l} \gamma^{0} = \sum_{i=1}^{N} |\phi_{i}\rangle\langle\phi_{i}| = \mathbf{1}_{(-\infty,\varepsilon_{\mathrm{F}}]}(H_{\rho^{0}}), \qquad \rho^{0}(\mathbf{r}) = \gamma^{0}(\mathbf{r},\mathbf{r}) = \sum_{i=1}^{N} |\phi_{i}(\mathbf{r})|^{2} \\ & H_{\rho^{0}}\phi_{i} = \varepsilon_{i}\phi_{i} \\ & \int_{\mathbb{R}^{3}} \phi_{i}\phi_{j} = \delta_{ij} \\ & \varepsilon_{1} < \varepsilon_{2} \leq \cdots \leq \varepsilon_{N} \quad \text{lowest } N \text{ eigenvalues of } H_{\rho^{0}} \\ & \mathbf{N=5} \\ & \mathbf{H}_{\rho^{0}} = -\frac{1}{2}\Delta + V_{\rho^{0}}^{\mathrm{KS}}, \qquad V_{\rho^{0}}^{\mathrm{KS}} = V^{\mathrm{ne}} + \rho^{0} \star |\cdot|^{-1} - \frac{4}{3}C_{\mathrm{X}}\rho^{0^{1/3}} \end{split}$$

## Nonlinear eigenvalue problem

### Mathematical and numerical analysis of the models arising in DFT

- 1. Proof of existence of a solution for neutral and positively charged systems
  - (a) for LDA :  $E_{\rm xc}^{\rm LDA}(\rho) = \int_{\mathbb{R}^3} e_{\rm xc}(\rho(\mathbf{r})) d\mathbf{r}$  (Le Bris 1993)
- (b) for GGA :  $E_{\rm xc}^{\rm GGA}(\rho) = \int_{\mathbb{R}^3} e_{\rm xc}(\rho(\mathbf{r}), \nabla \rho(\mathbf{r})) d\mathbf{r}$  but only for two electron systems (Anantharaman, E.C., submitted)
- 2. Construction and proof of convergence of some simple SCF algorithms (E.C., Le Bris, 2000-2003). A priori error estimates for Kohn-Sham LDA (E.C., Chakir, Maday, ongoing work)
- 3. Thermodynamical limits with  $E_{\rm xc}(\rho) = 0$ : perfect crystal (Catto, Le Bris, Lions 1998), crystals with local defects (E.C., Deleurence, Lewin, 2008)
- 4. A lot of work remains to be done!

Spectrum of the N-body Hamiltonian (operating on  $\mathcal{H}_e = \bigwedge_{i=1}^{N} L^2(\mathbb{R}^3)$ )

$$H_N = -\sum_{i=1}^{N} \frac{1}{2} \Delta_{\mathbf{r}_i} - \sum_{i=1}^{N} \sum_{k=1}^{M} \frac{z_k}{|\mathbf{r}_i - \mathbf{R}_k|} + \sum_{1 \le i < j \le N} \frac{1}{|\mathbf{r}_i - \mathbf{r}_j|} = -\frac{1}{2} \Delta + V$$

If 
$$Z = \sum_{k=1}^{M} z_k \ge N$$
 (neutral or positively charged system),  
-  $\sigma_{\text{ess}}(H_N) = [\Sigma_N, +\infty)$  with  $\Sigma_N < 0$  if  $N \ge 2$  and  $\Sigma_1 = 0$ ;

 $-H_N$  has an infinite sequence of finite multiplicity eigenvalues  $E^0 = \lambda_1(H_N) \leq \lambda_2(H_N) \leq \lambda_3(H_N) \leq \cdots$  converging to  $\Sigma_N$ 



### Notations :

- Electronic ground state (supposed to be non-degenerate)

$$H_N \Psi^0 = E^0 \psi^0 \qquad \qquad E^0 = \lambda_1(H_N)$$

$$-\operatorname{Let} \gamma = \lambda_2(H_N) - \lambda_1(H_N) > 0$$

– Let  $\Psi_I$  be a trial wavefunction, relatively close to  $\Psi_0$  for which the local fields

$$b(x) = \frac{\nabla \Psi_I(x)}{\Psi_I(x)}$$
 and  $E_L(x) = \frac{(H_N \Psi_I)(x)}{\Psi_I(x)} = -\frac{1}{2} \frac{\Delta \Psi_I(x)}{\Psi_I(x)} + V(x)$ 

are not too difficult to compute (finite sum of Slater determinants)

Let us consider the parabolic (imaginary time Schrödinger) equation

$$\begin{cases} \frac{\partial \phi}{\partial t} = -H_N \phi = \frac{1}{2} \Delta \phi - V \phi \\ \phi(0, x) = \Psi_I(x) \end{cases}$$
(4)

and

$$E(t) = \frac{(H_N \Psi_I, \phi(t))_{L^2}}{(\Psi_I, \phi(t))_{L^2}}.$$
(5)

One has

$$0 \leq E(t) - E^{0} \leq \frac{\left( (H_{N}\Psi_{I}, \Psi_{I})_{L^{2}} - E^{0} \right)}{(\Psi^{0}, \Psi_{I})_{L^{2}}^{2}} \exp(-\gamma t)$$

**Diffusion Monte Carlo** : simulation of (4)-(5) with probabilistic methods using variance reduction techniques (importance sampling).

Set  $f_1(t,x) = \Psi_I(x)\phi(t,x)$ . A simple calculation shows that

$$E(t) = \frac{(H_N \Psi_I, \phi(t))_{L^2}}{(\Psi_I, \phi(t))_{L^2}} = \frac{\int_{\mathbb{R}^3} (H_N \Psi_I)(x) \,\phi(t, x) \,dx}{\int_{\mathbb{R}^3} \Psi_I(x) \phi(t, x) \,dx} = \frac{\int_{\mathbb{R}^3} E_L(x) \,f_1(t, x) \,dx}{\int_{\mathbb{R}^3} f_1(t, x) \,dx}$$

and that  $f_1$  solves

$$\begin{cases} \frac{\partial f}{\partial t} = \frac{1}{2}\Delta f - \operatorname{div} (bf) - E_L f\\ f(0, x) = \Psi_I^2(x), \end{cases}$$

with

$$b(x) = \frac{\nabla \Psi_I(x)}{\Psi_I(x)} \quad \text{and} \quad E_L(x) = \frac{(H_N \Psi_I)(x)}{\Psi_I(x)} = -\frac{1}{2} \frac{\Delta \Psi_I(x)}{\Psi_I(x)} + V(x)$$

Interpretation of the equation on  $f_1$  in terms of stochastic process

$$\frac{\partial f}{\partial t} = \frac{1}{2}\Delta f - \operatorname{div} (bf) - E_L f$$

$$\downarrow \qquad \qquad \downarrow \qquad \qquad \downarrow$$
diffusion drift birth-death

One can then try to approximate E(t) by

$$E^{\text{DMC}}(t) = \frac{\mathbb{E}\left(E_L(X_t) \exp\left(-\int_0^t E_L(X_s)\right) ds\right)}{\mathbb{E}\left(\exp\left(-\int_0^t E_L(X_s) ds\right)\right)}$$

where  $(X_t)_{t\geq 0}$  is the stochastic process defined by

$$\begin{cases} dX_t = b(X_t) dt + dW_t \\ X_0 \sim \Psi_I^2. \end{cases}$$

With B. Jourdain et T. Lelièvre, we have proved the following results (M3AS 2006) : under some technical assumptions,

1. Because of the singularity of the drift  $b(x) = \frac{\nabla \Psi_I(x)}{\Psi_I(x)}$ , the trajectories defined by

$$\begin{cases} dX_t^x = b\left(X_t^x\right) \, dt + dW_t \\ X_0^x = x \end{cases}$$

cannot cross the nodal surfaces  $\Psi_I^{-1}(0)$ .

The random variable  $X_t^x$  has a density p(t, x, y) and the function

$$(x,y) \longmapsto \Psi_I(x)^2 p(t,x,y)$$

is symmetric.

### 2. It holds

$$E(t) = \frac{\int_{\mathbb{R}^3} E_L(x) f_1(t, x) dx}{\int_{\mathbb{R}^3} f_1(t, x) dx} \qquad E^{\text{DMC}}(t) = \frac{\int_{\mathbb{R}^3} E_L(x) f_2(t, x) dx}{\int_{\mathbb{R}^3} f_2(t, x) dx}$$

where  $f_1$  and  $f_2$  are two different weak solutions of

$$\begin{cases} \frac{\partial f}{\partial t} = \frac{1}{2}\Delta f - \operatorname{div} (bf) - E_L f\\ f(0, x) = \Psi_I^2(x), \end{cases}$$

# More precisely

$$f_1(t,x) = \Psi_I(x) \phi(t,x)$$

$$\begin{aligned} \frac{\partial \phi}{\partial t} &= \frac{1}{2} \Delta \phi - V \phi \\ \phi(0, x) &= \Psi_I(x), \end{aligned}$$

$$f_2(t,x) = \Psi_I(x) \phi_2(t,x)$$

$$\begin{cases} \frac{\partial \phi_2}{\partial t} = \frac{1}{2} \Delta \phi_2 - V \phi_2 \\ \phi_2(0, x) = \Psi_I(x) \\ \phi_2(t, x) = 0 \quad \text{on } \Psi_I^{-1}(0) \end{cases}$$

3. The function  $E^{\text{DMC}}(t)$  converges when t goes to  $+\infty$  to

$$\inf\left\{\langle\Psi, H_N\Psi\rangle, \quad \Psi \in \bigwedge_{i=1}^N H^1(\mathbb{R}^3), \quad \|\Psi\|_{L^2} = 1, \quad \Psi = 0 \text{ on } \Psi_I^{-1}(0)\right\}$$

which is an upper bound of the exact ground state energy

$$E^{0} = \inf\left\{ \langle \Psi, H_{N}\Psi \rangle, \quad \Psi \in \bigwedge_{i=1}^{N} H^{1}(\mathbb{R}^{3}), \quad \|\Psi\|_{L^{2}} = 1 \right\}$$

This mathematical analysis points out one of the main limitations of the Diffusion Monte Carlo method, well known by its users : using an importance function  $\Psi_I$  introduces a systematic error, except in the peculiar case when the nodal surfaces of  $\Psi^0$  and  $\Psi_I$  exactly coincide

# Mathematical and numerical challenges :

- 1. Analysis and improvement of the existing numerical schemes (stochastic particle methods)
- 2. Computation of interatomic forces
- 3. How to go beyond the fixed node approximation?

The (Fixed Node) Diffusion Monte Carlo method remains to date the reference method for accurate Quantum Monte Carlo simulations on large systems



$$S_0 \rightarrow S_2$$

 $\pm$